



Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

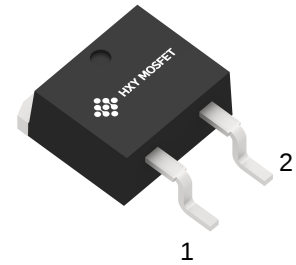
- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

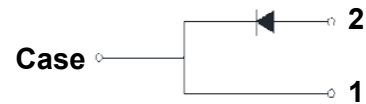
- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



Part Number	Package	Qty(PCS)
FFSB0865B-F085	TO-263N	800



TO-263N



Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	
V_{RSM}	Surge Peak Reverse Voltage	650	V	
I_F	Continuous Forward Current	24.1 11.3 6	A	$T_C=25^\circ\text{C}$ $T_C=135^\circ\text{C}$ $T_C=152^\circ\text{C}$
I_{FRM}	Repetitive Peak Forward Surge Current	30	A	$T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	60	A	$T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave
P_{tot}	Power Dissipation	100 43	W	$T_C=25^\circ\text{C}$ $T_C=110^\circ\text{C}$
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$	
$\int i^2 dt$	$i^2 dt$ value	18	A^2s	$T_C=25^\circ\text{C}$, $t_p = 10$ ms, Half Sine Wave



Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	650			V	
V_F	Forward Voltage		1.42 1.88	1.7 2.5	V	$I_F = 8\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 8\text{ A}$ $T_J = 175^\circ\text{C}$
I_R	Reverse Current		0.12 0.91	50 100	μA	$V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$
Q_C	Total Capacitive Charge		21		nC	$V_R = 400\text{ V}$ $T_J = 25^\circ\text{C}$
C	Total Capacitance		395 42 41		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$
E_C	Capacitance Stored Energy		5		μJ	$V_R = 400\text{ V}$

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.5	$^\circ\text{C/W}$

Typical Performance

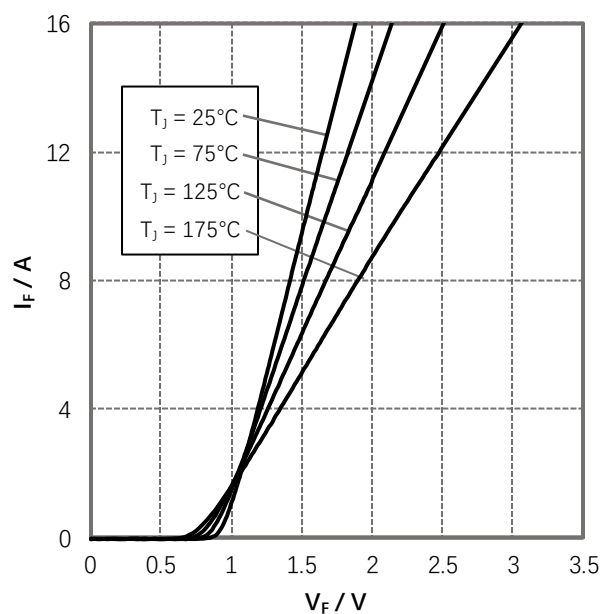


Figure 1. Forward Characteristics

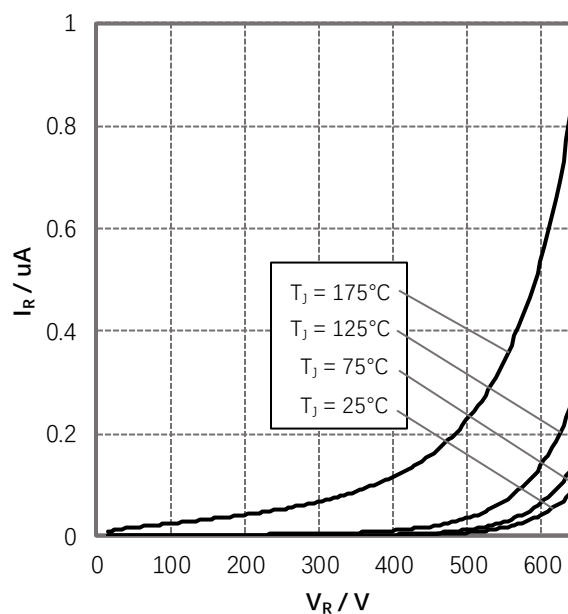


Figure 2. Reverse Characteristics

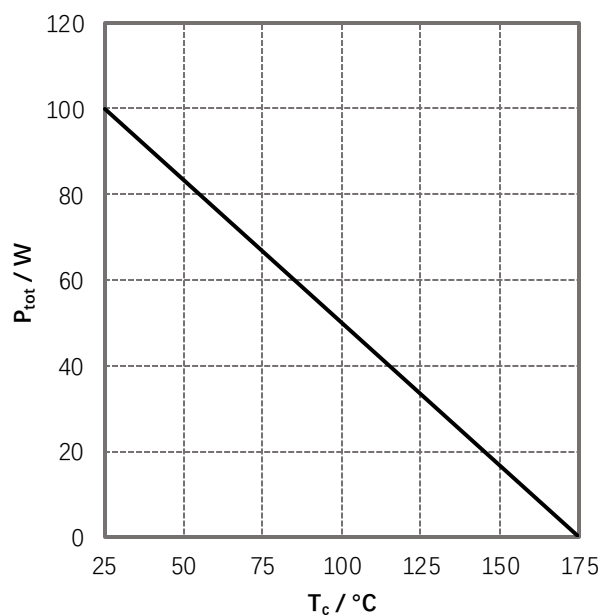


Figure 3. Power Derating

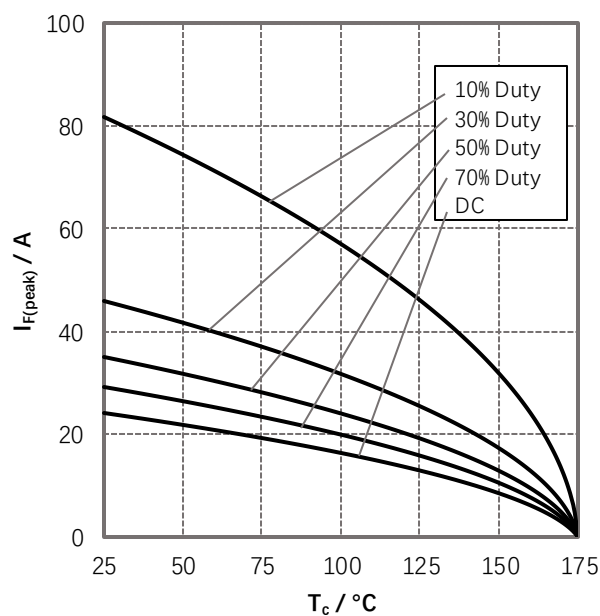


Figure 4. Current Derating

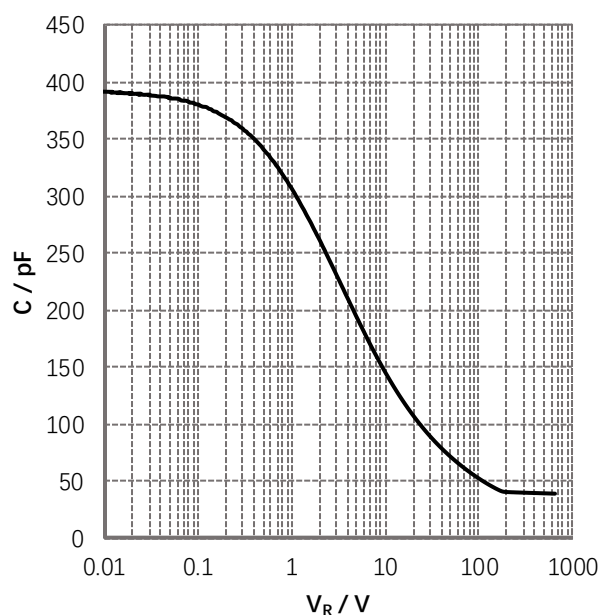


Figure 5. Capacitance vs. Reverse Voltage

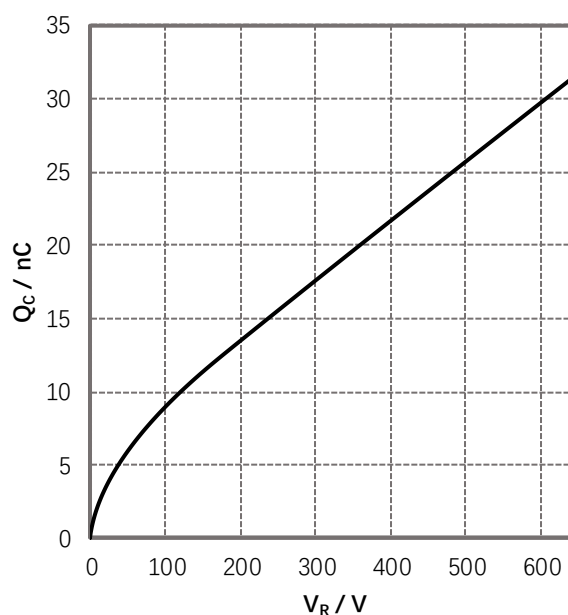


Figure 6. Total Capacitance Charge vs. Reverse Voltage

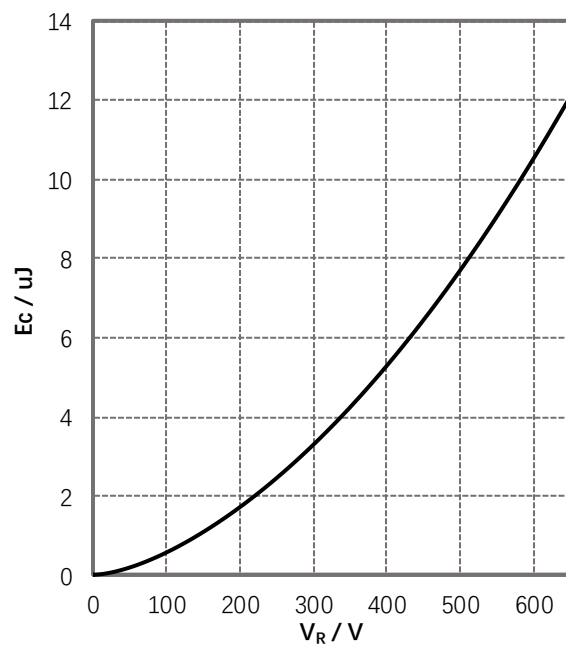


Figure 7. Capacitance Stored Energy

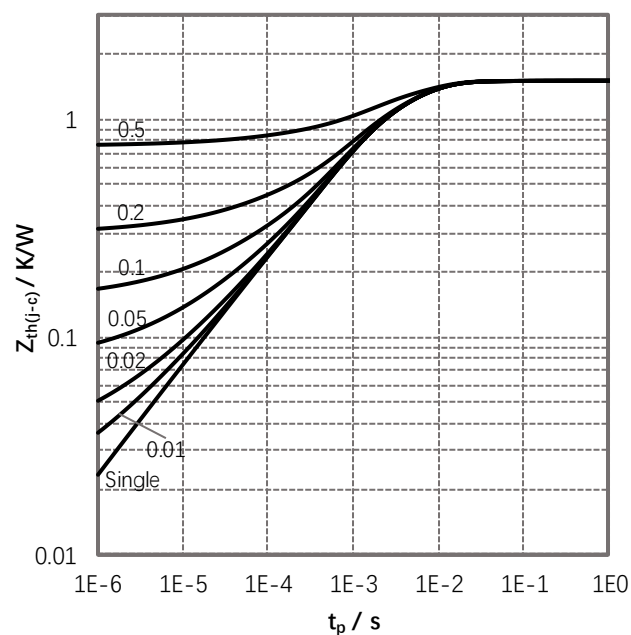
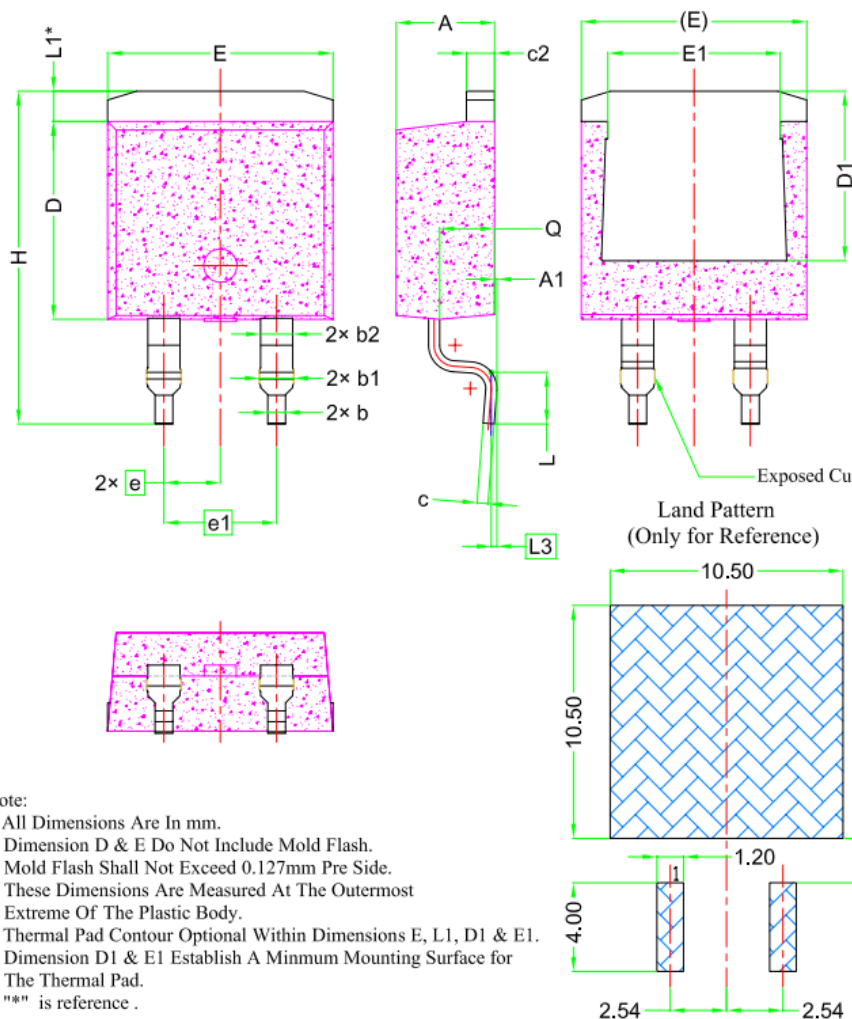


Figure 8. Transient Thermal Impedance



Package Information TO-263N



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	4.24	4.44	4.64
A1	0.00	0.10	0.25
b	0.70	0.80	0.90
b1	1.20	1.55	1.75
b2	1.20	1.45	1.70
c	0.40	0.50	0.60
c2	1.15	1.27	1.40
D	8.82	8.92	9.02
D1	6.86	7.65	—
E	9.96	10.16	10.36
E1	6.89	7.77	7.89
e	2.54 BSC		
e1	5.08 BSC		
H	14.61	15.00	15.88
L	1.78	2.32	2.79
L1	1.36 REF.		
L3	0.25 BSC		
Q	2.30	2.48	2.70

Note:

1. All Dimensions Are In mm.
2. Dimension D & E Do Not Include Mold Flash.
Mold Flash Shall Not Exceed 0.127mm Pre Side.
These Dimensions Are Measured At The Outermost
Extreme Of The Plastic Body.
3. Thermal Pad Contour Optional Within Dimensions E, L1, D1 & E1.
4. Dimension D1 & E1 Establish A Minmum Mounting Surface for
The Thermal Pad.
5. "*" is reference .



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